



Docket No.: 43890-449

PATENT

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retains

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re Application of

Hidenori KAMEI, et al.

Serial No.: 09/680,943

Group Art Unit: 2823

Filed: October 10, 2000

Examiner: G. R. Fourson III

For: P-TYPE NITRIDE SEMICONDUCTOR AND METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT

Hon. Assistant Commissioner for Patents
Washington, DC 20231

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed more than three months after the U.S. filing date AND before the mailing date of the first Office Action on the merits.

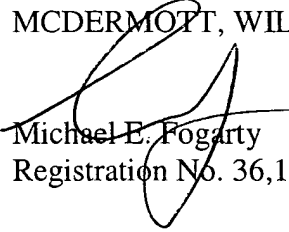
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Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

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